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Focus on three 'new' measurement topics . . .

- I. Filling the gap between microwaves and photonics
- II. Multi-physics more than just microwaves
- III. When digital becomes analogue



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Filling the gap between electronics and photonics





Many applications

THz electronics

Terahertz Monolithic Integrated Circuit (TMIC) InP amplifier (Northrop Grumman)

Radio Astronomy

ALMA – Atacama Large Millimeter/submillimeter Array Location: Atacama dessert, Northern Chile Telescope bandwidth: >950 GHz







Many applications

Security

Airports and stand-off detection Detecting weapons and other terrorist threats

Space

European Space Agency (ESA) ISMAR - International Sub-Millimetre Airborne Radiometer Instrument Observing precipitation and ice clouds (for climate change)







New measurements . . . going from GHz to THz

- Instrumentation waveguides
- Devices on-wafer



New measurements . . . going from GHz to THz

Instrumentation – waveguides

Devices – on-wafer



Metal waveguides – some history

- Use of metallic waveguide dates back to the early/mid 20th century
- First 'popular' waveguide: X-band (8.2 – 12.4 GHz)
- X-band aperture size: 0.9" × 0.4"
 23 mm × 10 mm





As frequencies get higher, waveguide gets smaller . . .

At 200 GHz Aperture: 1.30 mm \times 0.65 mm



At 1000 GHz (1 THz) Aperture: 250 $\mu m \times 125 \ \mu m$







1 THz waveguide . . . seen under a microscope (during a dimensional measurement)

Aperture =

 $250 \ \mu m \times 125 \ \mu m$





Dimensions measured using probe/vision systems

CMM (Coordinate Measuring Machines)

Waveguide apertures and flanges

New IEEE standards (1785)







Three new standards:

"IEEE Standard for Rectangular Metallic Waveguides and Their Interfaces for Frequencies of 110 GHz and Above"

- IEEE Std 1785.1-2012
- IEEE Std 1785.2-2016
- IEEE Std 1785.3-2016



♦IEEE

IEEE Std 1785.1-2012

Part 1: "Frequency Bands and Waveguide Dimensions"



IEEE STANDARDS ASSOCIATION

IEEE Standard for Rectangular Metallic Waveguides and Their Interfaces for Frequencies of 110 GHz and Above—

Part 1: Frequency Bands and Waveguide Dimensions

IEEE Microwave Theory and Techniques Society

Sponsored by the Standards Coordinating Committee

IEEE 3 Park Avenue New York, NY 10016-5997 USA

IEEE Std 1785.1™-2012

1 March 2013



IEEE Std 1785.2-2016

Part 2: "Waveguide Interfaces"





New York, NY 10016-5997 USA



IEEE Std 1785.3-2016

Part 3:

"Recommendations for Performance and Uncertainty Specifications" IEEE STANDARDS ASSOCIATION IEEE Recommended Practice for Rectangular Metallic Waveguides and Their Interfaces for Frequencies of 110 GHz and Above— Part 3: Recommendations for

Performance and Uncertainty Specifications

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Effects of waveguide aperture and interface tolerances





Waveguide measurement capability

- Vector Network Analyser (VNA) with high precision calibration kits
- University of Leeds / NPL partnership: Traceable VNA to 1.1 THz



Source: N M Ridler and R G Clarke, IEEE T-TST, 6 (1):2-11, Jan 2016.



University of Leeds / NPL traceable measurements to 1.1 THz

VNA dynamic range (60 dB)



VNA accuracy (3 dB @ 30 dB)



Source: N M Ridler and R G Clarke, IEEE T-TST, 6 (1):2-11, Jan 2016.



Filling the gap between microwaves and photonics Remaining challenges:

- Key Comparisons and CMCs in the 0.1 THz to 1.0 THz range
- Establish traceability services offering *comprehensive* frequency coverage
- Establish *regional* metrology facilities in Asia, Europe, North America, etc
- What about > 1 THz ??



New measurements . . . going from GHz to THz

- Instrumentation waveguides
- Devices on-wafer



Most devices are on a planar wafers

• We need a probe station and on-wafer probes to do measurements





For on-wafer measurements, best to calibrate at probe tips using on-wafer standards: 750 GHz to 1.1 THz





Source: Dominion MicroProbes Inc (DMPI) web-site: www.dmprobes.com



On-wafer calibration kits (calibration substrates)





Filling the gap between microwaves and photonics Remaining challenges:

- Measurement traceability!! . . . Yes or no?? (there is still no on-wafer traceability, even after >25 years)
- Many scientific challenges relating to very short wavelength propagation
- Many technological challenges due to differing dimensions and materials
- Establish *regional* metrology capabilities in Asia, Europe, North America, etc



Next topic . . .

I. Filling the gap between microwaves and photonics

II. Multi-physics – more than just microwaves

III. When digital becomes analogue



Multi-physics – more than just microwaves

Application area . . .

Telecommunications o 5G and beyond o Machine to Machine (M2M) o Internet of Things (IoT) o RF Nano-technology



The start of the communications revolution . . .

Alexander Graham Bell at the opening of the long-distance telephone line from New York to Chicago in 1892

(125 years ago)





Modern communications devices (power amplifiers, etc) require an holistic (multi-physics) approach to device testing

Microwave measurements

. . . and

Electromagnetic near-field scanning

. . . and

Thermal imaging

It would be great to do all this, at the same time !!



This approach is available at **n3m-labs** (the Nonlinear Microwave Measurement & Modelling Laboratories) at the University of Surrey and NPL in the UK

n3m-labs was opened in June 2016





Fixtured microwave measurements - large-signal; passive/active harmonic loadpull





On-wafer microwave measurements – large-signal; passive/active harmonic loadpull







Electromagnetic near-field scanning









Thermal imaging







n3m-labs capabilities:

- On-wafer/fixtured passive/active harmonic loadpull
- Two Nonlinear VNAs to 67 GHz
- High power RF sources
- On-wafer probe station (temperature: -40 °C to +200 °C)
- High-resolution thermal imaging (0.25 um and 50 ns)
- Near-field electromagnetic scanner
- Nonlinear device modelling software
- Compute cluster: 1064 cores, 5.5 TB RAM, GPUs...
- UK primary national measurement standards











Multi-physics – more than just microwaves Remaining challenges :

- Traceability for 'new' non-linear measurands (X-parameters, etc)
- Source-pull and Load-pull measurements ($Z_0 \neq 50$ ohms)
- Uncertainties in measurement-derived models
- Measurement site-to-site reproducibility





Final topic . . .

- I. Filling the gap between microwaves and photonics
- II. Multi-physics more than just microwaves

III. When digital becomes analogue



When digital becomes analogue

Applications:

- Computing
- Internet of Things (IoT)
- High-speed electronics (interconnects)
- Games (Wii, Playstation, Xbox)



Key technology: Printed Circuit Boards (PCBs) and component interconnects

Digital signals (ones and zeros: 1, 0, 0, ..., 0, 1, ...)



Leading edge contains many high frequency components



1. Pulse risetime





Risetime (seconds): bandwidth (hertz)

 $RT = \frac{0.35}{BW}$



Risetime = 10 ps Bandwidth = **35 GHz** mm-wave frequencies!





Utilities Help

Buttons MASK: 1000B-SX/LX (1.25 Gb/s) For measurements, we need: **Time-domain** and 165mV Ω M 125ps 400GS/s ET 2.5ps/pt Ch1 **Frequency-domain** Саггіег Frequency

Horiz/Acq

Trig

Display

Cursors

Measure

Masks Math



2. PCB component packing/interconnect – very high density

Use differential signals to avoid component-to-component interference





For measurements, we need:

Mixed-mode S-parameters:

- Differential-mode (DD)
- Common-mode (CC)
- Mode conversion: differential-to-common and vice versa (CD, DC)



	(S _{DD,11}	S _{DD,12}	S _{DC,11}	$S_{DC,12}$
_	S _{DD,21}	<i>S</i> _{DD,22}	S _{DC,21}	S _{DC,22}
	S _{CD,11}	S _{CD,12}	S _{CC,11}	S _{CC,12}
,	S _{CD,21}	S _{CD,22}	S _{CC,21}	$S_{CC,22}$



Component interference "victims" and aggressors"

- 3 devices
- Each device has 4 connections
- We need 12 "ports" to make these measurements





- 3. Multilayer PCBs
- Involves conductors and dielectrics sandwiched together
- Connections to embedded layers are difficult
- Via holes are drilled through layers to help with interconnects





Multi-layer PCBs





PCBs with several layers





Combined measurement architecture:

- Time-domain / Frequency-domain for Signal Integrity assessments
- Differential signals mixed-mode S-parameters
- Multi-port devices for victims and aggressors assessments
- Multi-layer microstrip / stripline transmission lines



Remaining challenges – when digital becomes analogue:

- Traceability and/or Best Practice on PCBs:
 - Time-domain / Frequency-domain equivalence
 - Mixed-mode S-parameters
 - Multi-layer PCBs
- Provide input to industry-level standards-making: IEEE (P370), IPC (TM650), etc
- 'Wire' interconnects at the nano-scale
- Establish *regional* metrology capabilities in Asia, Europe, North America, etc



Topics I haven't discussed (but are still very important):

- Terahertz time-domain systems (spectrometers, etc)
- Antenna beam-forming techniques for mm-wave communications
- Extreme impedance measurements for emerging nano-materials (graphene, etc)

Further reading – THz metrology



- The 2017 Terahertz Science and Technology Roadmap 46 co-authors, J Phys D, Vol 50, No 4, 043001 (49pp), Feb 2017
- Metrology State-of-the-art and Challenges in Broadband Phasesensitive Terahertz Measurements
 M Naftaly, R G Clarke, D A Humphreys, N M Ridler, Proc IEEE, Jan 2017
- Establishing Traceability to the International System of Units for Scattering Parameter Measurements from 750 GHz to 1.1 THz
 N M Ridler, R G Clarke, IEEE Trans TST Vol 6, No 1, pp 2-11, Jan 2016
- Terahertz Metrology Mira Naftaly (Editor), Artech House, 2015